

T495A106M010ATE2K5

General Information

Series

Style

Dielectric

Description

T495, Tantalum, MnO2 Tantalum, Commercial Grade, 10 uF, 20%, 10 VDC, SMD, MnO2, Molded, Low ESR, 2.5 Ohms, 3216, 1.8 mm, 0.8 mm

T495

MnO2 Tantalum

6% 120Hz 25C

1uA (5min 25°C)

2500 mOhms (100kHz 25C)

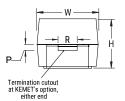
173 mA (rms, 100kHz 25C), 155.7 mA (rms, 85C), 69.2 mA (rms, 125C)

N/A

SMD, MnO2, Molded, Low ESR

SMD Chip

CATHODE (-) END VIEW

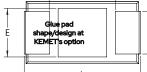


ANODE (+) END VIEW

Dimensions

В S - G · -Sвоттом и — A —

SIDE VIEW



Click here for the 3D model.

	Features RoHS Termination AEC-Q200 Typical Component Weight Shelf Life	Low ESR Yes Tin No 58.6 mg 156 Weeks
	MSL	1
	Specifications	
nm	Capacitance	10 uF
ım	Tolerance	20%
ım	Voltage DC	10 VDC (85C), 6.7 VDC (125C)
	Temperature Range	-55/+125°C
).3mm	Rated Temperature	85°C

Dissipation Factor Failure Rate

Ripple Current

ESR

Billicitorio			
L	3.2mm +/-0.2mm		
W	1.6mm +/-0.2mm		
н	1.6mm +/-0.2mm		
Т	0.13mm REF		
S	0.8mm +0.2/-0.3mm		
F	1.2mm +/-0.1mm		
Α	1.2mm MIN		
В	0.4mm +/-0.15mm		
E	1.3mm REF		
G	1.1mm REF		
Р	0.4mm REF		
R	0.4mm REF		
Х	0.1mm +/-0.1mm REF		

2000

Р	0.4mm REF	Leakage Current
R	0.4mm REF	
Х	0.1mm +/-0.1mm REF	
Packaging Specifications		
Packaging	T&R, 178mm	

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

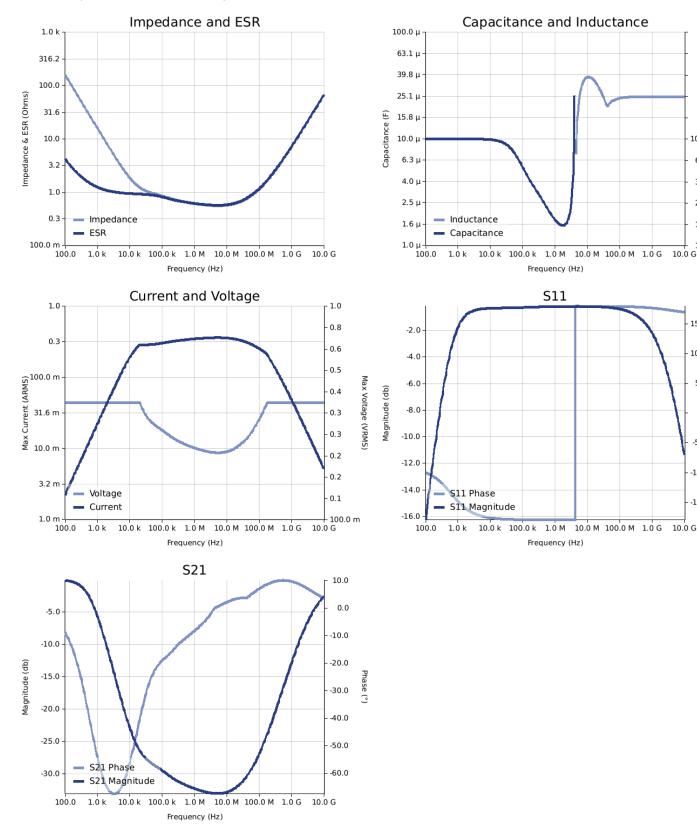
Packaging Quantity



T495, Tantalum, MnO2 Tantalum, Commercial Grade, 10 uF, 20%, 10 VDC, SMD, MnO2, Molded, Low ESR, 2.5 Ohms, 3216, 1.8 mm, 0.8 mm

Simulations

For the complete simulation environment please visit K-SIM.



1.0 n

0.6 n

0.4 n

0.3 n

100.0 p tan

0.2 n a

63.1 p 🗄

39.8 p

25.1 p

15.8 p

10.0 p

150.0

100.0

50.0

0.0

-50.0

-100.0

-150.0

10.0 G

Phase (°)



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These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated. The effects shown herein are based on measured data from a multiple part sample of the parts in question. Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance. The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.
 Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.